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N-Channel 100 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ) (Typ.)	I _D (A) ^a	Q _g (Typ.)			
100	3.2 at V _{GS} = 10 V	190	78 nC			

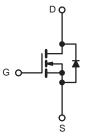
FEATURES

- DT-SJ Power MOSFET
- Very low on-resistance
- Excellent gate charge x R_{DS(on)} product(FOM)



APPLICATIONS

- DC-DC Converters
- Ideal for high-frequency switching and synchronous rectification



N-Channel MOSFET

TO-247 Pin Configuration



ABSOLUTE MAXIMUM RATINGS ($\Gamma_{\rm C}$ = 25 °C, unless othe	rwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V _{DS}	100	V		
Gate-Source Voltage	V _{GS}	± 20	7 v		
Continuous Drain Current (T. – 150 °C)8	T _C = 25 °C	1	190		
Continuous Drain Current (T _J = 150 °C) ^a	T _C = 100 °C	I _D	123	А	
Pulsed Drain Current ^b	I _{DM}	I _{DM} 760			
Single Avalanche Energy	E _{AS}	1150	mJ		
Maximum Dawar Dissinations	T _C = 25 °C	D	348 ^c	W	
Maximum Power Dissipation ^c	T _C = 100 °C	P _D	139	VV	
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	-55 to +150			
Soldering Recommendations (Peak Temperature		260	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	LIMIT	UNIT			
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	32	°C ///			
Junction-to-Case (Drain)	R _{thJC}	0.36	°C/W			

Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. $\,$ Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R_{8JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.



SPECIFICATIONS ($T_J = 25 ^{\circ}C$,	unless oth	erwise noted)				
PARAMETER	SYMBOL	TEST CONDITIONS	T CONDITIONS MIN. TYP.			UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	4	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	=	± 100	nA
Zoro Cata Voltago Prain Current		V _{DS} = 100 V, V _{GS} = 0 V	-	-	1	μΑ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V, T _J = 125 °C	-	-	100	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	190	-	-	Α
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 30 A	-	3.2	3.9	mΩ
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 5 \text{ V}, I_D = 30 \text{ A}$		55	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	5630	-	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 50 V, f = 1 MHz	-	632	-	pF
Reverse Transfer Capacitance	C _{rss}		-	29	-	
Total Gate Charge ^c	Qg		-	78	-	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 30 \text{ A}$	-	21	-	nC
Gate-Drain Charge ^c	Q_{gd}		-	13.6	-	
Gate Resistance	R_g	f = 1 MHz	-	0.8	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	29	-	
Rise Time ^c	t _r	$V_{DS} = 50 \text{ V}, I_{D} = 30 \text{ A}, R_{g} = 2.5 \Omega$	-	35	-	
Turn-Off Delay Time ^c	t _{d(off)}	V _{GS} = 10 V	-	52	-	ns
Fall Time ^c	t _f		-	22	-	
Drain-Source Body Diode Ratings and	Characterist	ti cs ^b (T _C = 25 °C)		_		
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	-	-	190	А
Pulsed Current (t = 100 µs)	I _{SM}		-	-	1150	А
Forward Voltage ^a	V _{SD}	I _F = 2 A, V _{GS} = 0 V	-	-	1.2	V
Reverse Recovery Time	t _{rr}	1 20 A di/dt 100 A/:	-	75	-	ns
Reverse Recovery Charge	Q _{rr}	$I_F = 30 \text{ A, di/dt} = 100 \text{ A/}\mu\text{s}$	-	160	-	nC

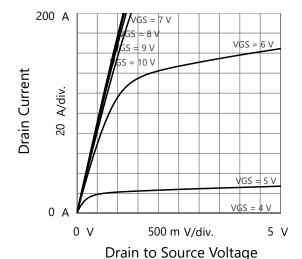
Notes

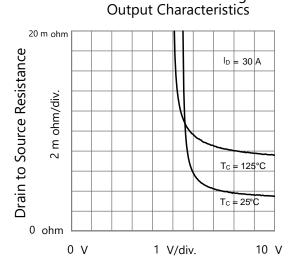
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

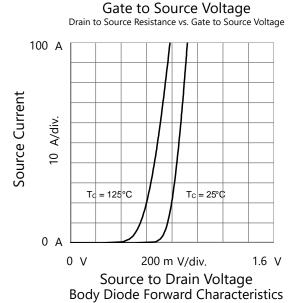
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

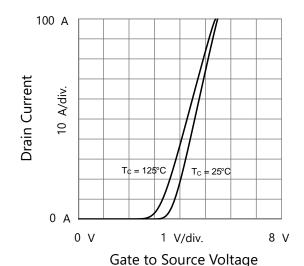


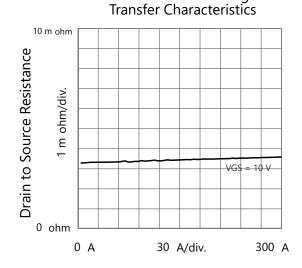
TYPICAL CHARACTERISTICS (25 C, unless otherwise noted)

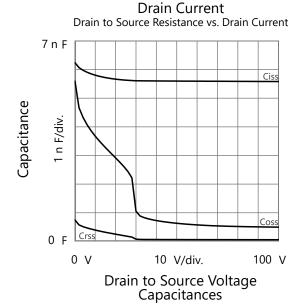






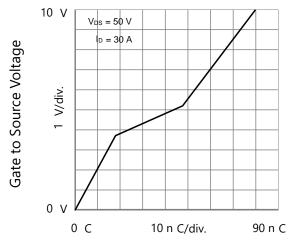




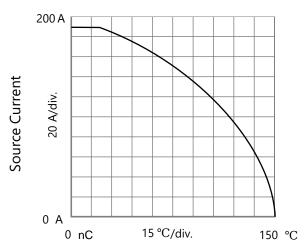




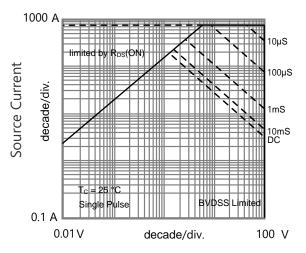
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



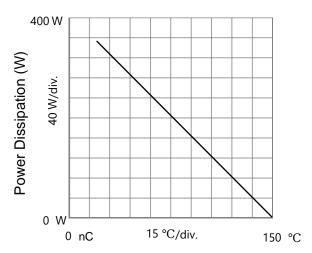
Gate Charge
Gate to Source Voltage vs. GateCharge



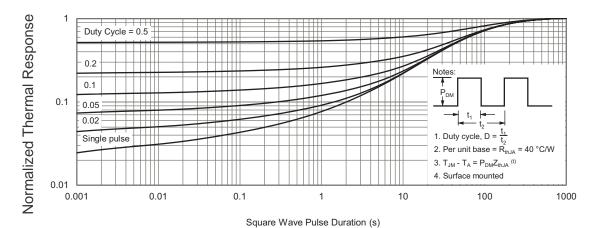
T_C - Case Temperature



Source to Drain Voltage Safe Operating Area, Junction-to-Ambient



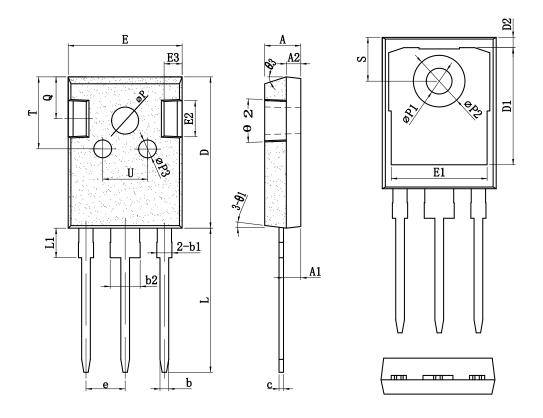
T_C - Case Temperature



Normalized Thermal Transient Impedance



TO-247_3L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.60	5.00	5.40	e	2.10	5.44	5.70
A1	2.10	2.41	2.70	L	19.00	19.98	21.00
A2	1.70	2.00	2.30	L1	-	-	4.50
b	1.00	1.20	1.40	ФР	3.30	3.70	4.00
b1	1.80	2.10	2.40	ФР1	3.25	3.55	3.85
b2	2.80	3.10	3.40	ФР2	6.80	7.18	7.60
С	0.45	0.60	0.75	ФР3	2.30	2.50	3.30
D	19.00	21.00	23.00	Q	5.50	5.80	6.30
D1	16.00	16.55	17.00	S	5.60	6.15	6.30
D2	0.95	1.20	1.45	T	9.50	10.00	10.50
E	15.70	15.80	16.50	U	6.00	ī	8.00
E1	12.80	13.25	13.70	θ1	5°	7°	9°
E2	4.20	5.00	5.30	θ2	1°	3°	5°
E3	2.20	2.50	2.80	θ3	13°	15°	17°





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